(30) Priority Data:

1008352

## WORLD INTELLECTUAL PROPERTY ORGANIZATION. International Bureau



# INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

WO 99/42904 (11) International Publication Number: (51) International Patent Classification 6: A1 26 August 1999 (26.08.99) (43) International Publication Date: G03F 7/20

NĿ

PCT/NL99/00090 (21) International Application Number:

19 February 1999 (19.02.99) (22) International Filing Date:

(71) Applicant (for all designated States except US): STICHTING VOOR DE TECHNISCHE WETENSCHAPPEN [NL/NL];

19 February 1998 (19.02.98)

Raadstede 15/19, NL-3431 HA Nieuwegein (NL).

(72) Inventor; and (75) Inventor/Applicant (for US only): SHMAENOK, Leonid [NL/NL]; Daalderburg 8, NL-3437 SW Nieuwegein (NL).

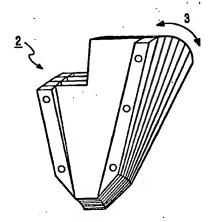
(74) Agent: VAN BREDA, Jacques; Octrooibureau Los en Stigter B.V., Weteringschans 96, NL-1017 XS Amsterdam (NL).

(81) Designated States: AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZW, ARIPO patent (GH, GM, KE, LS, MW, SD, SZ, UG, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG).

Published

With international search report. In English translation (filed in Dutch).

(54) Title: FILTER FOR EXTREME ULTRAVIOLET LITHOGRAPHY



(57) Abstract

The invention relates to an apparatus suited, for example, for extreme ultraviolet lithography, comprising a radiation source and a processing organ for processing the radiation from the radiation source. Between the radiation source and the processing organ a filter is placed, which in the radial direction from the radiation source, comprises a plurality of foils or plates.

## FOR THE PURPOSES OF INFORMATION ONLY

Codes used to identify States party to the PCT on the front pages of pamphlets publishing international applications under the PCT.

AL AM AT AU AZ BA BB BF BG BJ BR CA CF CG CH CI CM CN CU DE DK	Albania Armenia Austria Austria Australia Azerbaijan Bosnia and Herzegovina Barbados Belgium Burkina Faso Bulgaria Benin Brazil Belarus Canada Central African Republic Congo Switzerland Côte d'Ivoire Cameroon China Cuba Czech Republic Germany Denmark	ES FI FR GA GB GH GN GR HU IE IL IS IT JP KE KG KP LC LI LK LR	Spain Finland France Gabon United Kingdom Georgia Ghana Guinea Greece Hungary Ireland Israel Iceland Italy Japan Kenya Kyrgyzstan Democratic People's Republic of Korea Republic of Korea Razakstan Saint Lucia Liechtenstein Sri Lanka	LS LT LU LV MC MC MG MK MN MR MN NN NE NL NO NZ PL PT RO SE SC	Lesotho Lithuania Luxembourg Larvia Monaco Republic of Moldova Madagascar The former Yugoslav Republic of Macedonia Mali Mongolia Mauritania Malawi Mexico Niger Netherlands Norway New Zealand Poland Portugal Romania Russian Federation Sudan Sweden Singapore	SI SK SN SZ TD TG TJ TM TR TT UA UG US VN YU ZW	Slovenia Slovakia Senegal Swaziland Chad Togo Tajikistan Turkmenistan Turkey Trinidad and Tobago Ukraine Uganda United States of America Uzbekistan Viet Nam Yugoslavia Zimbabwe
		LK					:

## FILTER FOR EXTREME ULTRAVIOLET LITHOGRAPHY

The invention relates to an apparatus comprising a radiation source and a processing organ for processing the radiation from the radiation source.

Such an apparatus may be used in the production of integrated circuits, that is to say in a lithographical application. The invention may also be applied in various other fields. For a good understanding of the invention, however, a lithographical application will serve well as illustration. Continuous attempts are made to make integrated circuits smaller and smaller in order to improve the processing speed of the integrated circuits.

According to the prior art, such integrated circuits are manufactured chiefly by using lithography with visible and ultraviolet light. With these known technologies, it is possible to manufacture integrated circuits that may be as short as 120 nanometres. The ultraviolet light used with said circuits has a wavelength of 193 nanometres. The known techniques do not allow a further decrease of the dimensions of the integrated circuits, and a possible solution is the use of lithography on the basis of extreme ultraviolet light. Such light has a wavelength of 13 nanometres. The known optical elements cannot be used at this wavelength. The known mirrors and lenses absorb too large a portion of the extreme ultraviolet light. In order to allow for this, the processing organ for processing the radiation from the radiation source is 25 a multi-layer mirror which consists of 40 or more molybdenum layers alternating with silicon layers.

In such an apparatus for extreme ultraviolet lithography a laser plasma source is used to generate a plasma
by heating an object by means of a laser source of high
energy density, for example of at least 1011W/cm2. The

object heated by the laser will function as source of secondary emission of mainly shortwave radiation. However, this will also release undesirable particles and atoms producing the effect of debris in the apparatus. The objective of the invention is to prevent the production of said debris.

wo 96/10324 discloses such an apparatus for the generation of radiation. This apparatus uses a fast rotating target which is heated by the laser source and which produces the secondary emission. Due to the kinetic energy of the particles formed from the plasma on the rotating target, this apparatus has a filtering effect in respect of the so-called macro-particles. However, trapping atoms and in particular the fastest micro-particles, is not possible in this known apparatus.

According to the invention this possibility is now provided, by the apparatus being characterized in that a filter is placed between the radiation source and the processing organ which filter, in the radial direction from the radiation source, comprises a plurality of foils or plates. Surprisingly it has been shown that this very simple measure not only makes it possible to trap atoms and micro-particles, but also clusters of such micro-particles, respectively the smallest macro-particles.

A first preferred embodiment of the apparatus according to the invention is characterized in that the foils or plates are positioned in a honeycomb construction.

A second preferred embodiment of the apparatus

30 according to the invention is characterized in that the
foils or plates are cone-shaped and are positioned
concentrically.

Preferably, in the radial direction the foils or plates are positioned such as to be evenly distributed in relation to one another.

Such an apparatus is used with a buffer gas in which the radiation source and the processing organ are placed. Appropriately, the distance between the radiation source and the filter's proximal end in relation to the

25

radiation source is then selected subject to the pressure and the type of buffer gas. A very suitable choice of buffer gas is krypton, whose pressure is 0.5 Torr, and the distance between the radiation source and the proximal end of the filter is 5 cm. This setting affords sufficient opportunity for the particles to be trapped in the filter to take on the temperature of the buffer gas, for example room temperature, thereby sufficiently reducing the particle's velocity before it enters the filter.

It is further desirable to select the length of the filter, which is formed by the distance between the filter's proximal end and its distal end in relation to the radiation source, subject to the pressure of the buffer gas and the form of the filter. Especially the gas 15 pressure determines the mean free path length for the particles to be trapped; a lower gas pressure corresponds to an increased free path length. This can be partially compensated by the form of the filter. For example, using the above-mentioned honeycomb construction provides a larger surface area, affording greater opportunity for the particles to actually be trapped.

It has been shown that good results can be obtained when the length of the filter is at least 1 cm. This filter length corresponds with a usual gas pressure of, for example, 100 mTorr.

As already mentioned above, the apparatus is operational at room temperature. The measure of maintaining the filter at a temperature which is approximately below room temperature, allows the residence time of the atoms and particles trapped on a foil or plate to be increased, and accordingly the effectiveness of the filter to be improved.

It is further desirable that the number of plates in the filter should be adjusted subject to the thickness of each plate and the desired optical transparency of the filter as determined by the formula

30

In this way the light output of the integral appar-5 atus can be maintained at an adequate level, while the effectiveness of the filter can still be 100%. The apparatus is then preferably characterized in that the number of plates is adjusted such that the distance between two plates is approximately 1 mm.

The effectiveness of the filter may be improved further by roughening the surface of the plates.

The invention is further embodied in a separate filter for suppressing undesirable atomic and microscopic particles emitted by a radiation source, characterized by a plurality of plates positioned substantially parallel in relation to one another, for trapping atomic and microscopic particles on their respective surfaces.

Such a separate filter is preferably characterized in that the plates are directed radially from an imaginary point. This makes it ideal for use in association with a point-like radiation source.

The invention will now be explained in more detail with reference to the drawing, in which

Fig. 1 shows schematically a radiation source 25 together with a filter according to the invention;

Fig. 2 shows a preferred embodiment of the filter according to the invention; and

Fig. 3 shows schematically two more preferred embodiments of the filter according to the invention.

In the Figs., identical reference numbers relate to similar parts.

Fig. 1 shows a radiation source indicated by reference number 1, and a filter which is generally indicated by reference number 2. The processing organ that is used in the apparatus for, for example, extreme ultraviolet lithography, is not shown. This processing organ is located at the side of the filter 2 facing away from the radiation source 1. The filter 2 comprises a number of plates 3 positioned in a radial direction from the radi-

30

ation source 1. It is possible to position said plates in a honeycomb construction, or as a plurality of concentrical cones as shown in Fig. 3.

Figs. 1 and 2 show that in the direction of radiation from the source 1, the plates are positioned such as to be evenly distributed next to one another. The proximal end 4 of the filter 2 is at a distance X from the radiation source 1, which distance is selected depending on the pressure and the type of buffer gas in which the radiation source 1, the processing organ (not shown), and also 10 the filter 2, are placed. If the apparatus is used for extreme ultraviolet lithography, the buffer gas is preferably krypton having a pressure of 0.5 Torr, and the value of X may be 5 cm. The length of the plates of the filter is indicated by L. The value of L is selected depending on 15 the pressure of the buffer gas and the form of the filter 2. The value of L, that is to say the length of the filter, is at least 1 cm. In Fig. 1, this value is approximately 10 cm. The thickness of the plates 3 may be, for example, 0.1 mm, and the spacing between the plates at the side nearest the radiation source 1, may be approximately 1 mm. This may result in an optical transparency of the filter 2, which is determined by the formula

d + d × 100 %

in which d = the distance between two plates of the filter at the proximal side of the filter; and  $d_f$  = the thickness of a plate of the filter.

The effectiveness of the filter can be promoted if the surface of the plates 3 is slightly roughened.

When the apparatus is used for extreme ultraviolet lithography, radiation is used having a wavelength of 13.5 nanometres. Various inert gasses may be used as buffer gas, such as helium and krypton which, compared with other gasses have the lowest absorption coefficient at this wavelength. Krypton is better able to meet the requirements of the present application because the atomic mass of krypton is more compatible with that of the atomic- and

micro-particles emitted by the radiation source, which augments the inhibition of said undesirable particles. The krypton gas used is maintained at a pressure of at least several mTorr. It should be noted that taken over a distance of 20 cm at a pressure of 0.5 Torr, the optical transparency of krypton for the desired radiation is approximately 90%. The filter used in the apparatus is comprised of copper plates (other materials are also possible) which have a length of 7 cm and are positioned at 2 cm from the radiation source. At a plate thickness of 0.2 mm and with the plates being spaced at approximately 0.8 mm at the side of the radiation source, the filter will have a geometrical transparency of approximately 80%. The effectiveness of the filter was measured at room tem-15 perature and at a temperature of approximately -90°C. At both these temperatures the effectiveness of the filter was shown to be very high, almost 100.

It will be clear to the person skilled in the art
that the various dimensions of the filter forming part of
20 the apparatus according to the invention, as well as the
distance from the filter to the radiation source, has to
be determined in practice on the basis of the above-mentioned inter-relating ratios. It is therefore possible to
apply diverse variations to the above description, without
25 departing from the idea of the invention as specified in
the appended claims.

#### CLAIMS

- 1. An apparatus suited, for example, for extreme ultraviolet lithography, comprising a radiation source and a processing organ for processing the radiation from the radiation source, characterized in that a filter is placed between the radiation source and the processing organ which filter, in the radial direction from the radiation source, comprises a plurality of foils or plates.
- 2. An apparatus according to claim 1, characterized in that the foils or plates are positioned in a honeycomb construction.
- 3. An apparatus according to claim 1, characterized in that the foils or plates are cone-shaped and are positioned concentrically.
- 4. An apparatus according to one of the claims 1-3, characterized in that in the radial direction the foils or plates are positioned such as to be evenly distributed in relation to one another.
- 5. An apparatus according to one of the claims 1-4, wherein the radiation source and the processing organ are placed in a buffer gas, characterized in that the distance between the radiation source and the filter's proximal end in relation to the radiation source is selected subject to the pressure and the type of buffer gas.
- 6. An apparatus according to claim 5, characterized in that the buffer gas is krypton, that the pressure is at least approximately 0.1 Torr, and the distance between the radiation source and the proximal end of the filter is 5 cm.
- 7. An apparatus according to one of the preceding claims, characterized in that the length of the filter, which is formed by the distance between the filter's proximal end and its distal end in relation to the radiation source, is selected subject to the pressure of the buffer gas and the form of the filter.
- 35 8. An apparatus according to claim 7, characterized in that the length of the filter is at least 1 cm.

15

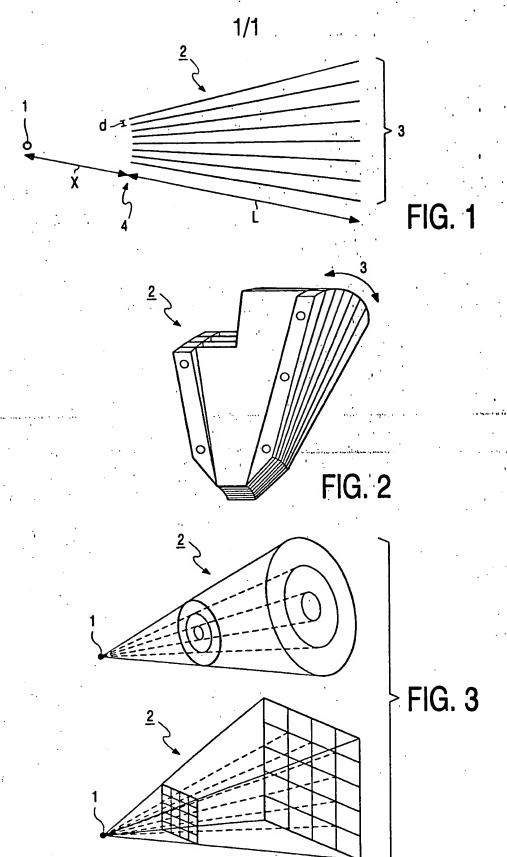
25

- 9. An apparatus according to one of the preceding claims, characterized in that the filter is maintained at a temperature which is below room temperature.
- 10. An apparatus according to one of the claims 19, characterized in that the number of plates in the filter is adjusted subject to the thickness of each plate and
  the desired optical transparency of the filter as determined by the formula

$$\frac{d}{d + d_{\ell}} \times 100 \%$$

 $d_{\mathbf{f}}$  = the thickness of a plate of the filter.

- 11. An apparatus according to claim 10, characterized in that the number of plates is adjusted such that the distance between two plates is approximately 1 mm.
- 12. An apparatus according to one of the preceding claims, characterized in that the surface of the plates is 20 rough.
  - 13. A filter for suppressing undesired atomic and microscopic particles which are emitted by a radiation source, characterized in that a plurality of plates are positioned substantially parallel in relation to one another, for trapping atomic and microscopic particles on their respective surfaces.
  - 14. A filter according to claim 13, characterized in that the plates are directed radially from an imaginary point.



### INTERNATIONAL SEARCH REPORT

inte onel Application No PCT/NL 99/00090

	FICATION OF SUBJECT MATTER G03F7/20				
I IPC 6					
ļ			•		
According to	o International Palent Classification (IPC) or to both national class	ification and IPC	·		
B. FIELDS	SEARCHED	notion symbols)	<del></del>		
Minimum do	ocumentation searched (classification system followed by classific G03F	cation symbols)			
1100					
	<u> </u>	at such documents are included, in the fields of	earched		
Documenta	tion searched other than minimum documentation to the extent th	at out in outuinents are included in the fields 6	•		
<u></u>			· · ·		
Electronic d	data base consulted during the international search (name of data	base and, where practical, search terms used	a)		
	* , .				
C. DOCUM	ENTS CONSIDERED TO BE RELEVANT	1.			
Category *	Citation of document, with indication, where appropriate, of the	relevant passages	Relevant to claim No.		
			+		
x	VARTANIAN M ET AL: "POLYCAPILL	ARY	1,3,4,		
[ "	COLLIMATOR FOR POINT SOURCE PRO	YIMIX	13,14		
1	X-RAY LITHOGRAPHY"	ECHNOLOGY			
	JOURNAL OF VACUUM SCIENCE AND T	ECHNOLUGI:	,		
	vol. 11, no. 6, 1 November 1993	, pages	La companyation of the		
١.	3003-3007, XP000423451				
	see page 3003, right-hand colum	nn, last 🕛 🦯			
in the state of th	paragraph; figures 2,3	e di amira i	w figures on the Standard of Standards to emble		
x	US 4 837 794 A (RIORDAN JOHN C	ET AL)	1,3,4,		
<b>  ^</b> .	6 June 198 <b>9</b>	•	13,14		
	see column 2, line 55 - column	3, line 2			
ĺ	see figure 3	•			
		-/			
l .					
·	·				
	<u> </u>	-			
X Furt	her documents are listed in the continuation of box C.	Patent family members are listed	d in annex.		
• Special ca	ategories of cited documents :	"T" later document published after the int or priority date and not in conflict with	ternational filing date		
"A" docume	ent defining the general state of the art which is not dered to be of particular relevance	cited to understand the principle or the invention	heary underlying the		
"E" earlier o	document but published on or after the international	"X" document of particular relevance; the	claimed invention		
"L" docume	ent which may throw doubts on priority claim(s) or	cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone			
which citation	is cited to establish the publication cate of another n or other special reason (as specified)	"Y" document of particular relevance; the cannot be considered to involve an in	nventive step when the		
other i	ent referring to an oral disclosure, use, exhibition or means	document is combined with one or ments, such combination being obvious	nore other such docu-		
"P" docume	ent published prior to the international filing date but han the priority date claimed	in the art. "&" document member of the same patent family			
	actual completion of the international search	Date of mailing of the international se			
	7 April 1999	06/05/1999			
		Authorized officer	<u> </u>		
Name and r	mailing address of the ISA European Patent Office, P.B. 5818 Patentlaan 2	. Delivered direct	: •		
	NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl.	Heryet, C			
1 '	Fax: (+31-70) 340-3016				

1

### INTERNATIONAL SEARCH REPORT

Inte anal Application No PCT/NL 99/00090

C.(Continue	tion) DOCUMENTS CONSIDERED TO BE RELEVANT  Citation of document, with indication where appropriate, of the relevant passages	. Relevant to claim No.
X	US 4 242 588 A (SILK JOHN K ET AL) 30 December 1980 see column 5, line 51 - column 6, line 3 see figure 2	1,13,14
<b>x</b> '	PATENT ABSTRACTS OF JAPAN vol. 095, no. 010, 30 November 1995 & JP 07 180042 A (NEC CORP), 18 July 1995	13,14
x	see abstract; figure 2  "COLLIMATOR FOR X-RAY LITHOGRAPHY"  IBM TECHNICAL DISCLOSURE BULLETIN,  vol. 33, no. 4, 1 September 1990, page  278/279 XP000106428  see the whole document	13
	see the whole document	
: .		and the best of the second
y regulariyani y 1 g		
	the sea productive and the season of the sea	the second section of the
,		
·		
• ·		

1

### INTERNATIONAL SEARCH REPORT

Information on patent family members

Inte anal Application No PCT/NL 99/00090

Patent document cited in search report		Publication date	Patent family member(s)	ı	Publication date
US 4837794	Α	06-06-1989	CA 12339 EP 01824 JP 611586	77 A	08-03-1988 28-05-1986 18-07-1986
US 4242588	Α .	30-12-1980	DE 300109 JP 11630 JP 560279 JP 570536	73 C 80 A	26-02-1981 10-08-1983 18-03-1981 13-11-1982